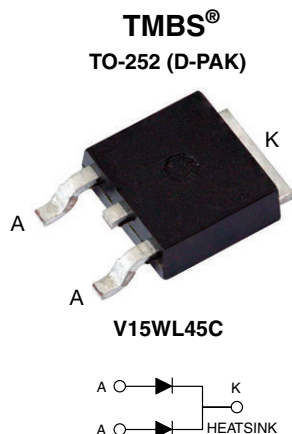


Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.38 \text{ V}$ at $I_F = 3 \text{ A}$



FEATURES

- Trench MOS Schottky technology
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 7.5 A
V_{RRM}	45 V
I_{FSM}	90 A
V_F at $I_F = 7.5 \text{ A}$ ($T_A = 125 \text{ °C}$)	0.40 V
T_J max.	150 °C
Package	TO-252 (D-PAK)
Diode variation	Dual common cathode

MECHANICAL DATA

Case: TO-252 (D-PAK)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V15WL45C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	15	A
		7.5	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	90	A
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C

**ELECTRICAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 3\text{ A}$	$V_F^{(1)}$	0.41	-	V
	$I_F = 7.5\text{ A}$		0.47	0.56	
	$I_F = 3\text{ A}$		0.30	-	
	$I_F = 7.5\text{ A}$		0.40	0.49	
Reverse current per diode	$V_R = 45\text{ V}$	$I_R^{(2)}$	-	1300	μA
			13	36	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
(2) Pulse test: Pulse width $\leq 5\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	V15WL45C	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	2.6
	per device		1.3
	per device	$R_{\theta JA}^{(1)(2)}$	65

Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
(2) Free air, without heatsink

ORDERING INFORMATION (Example)

PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
V15WL45C-M3/I	0.38	I	2500/reel	13" diameter plastic tape and reel

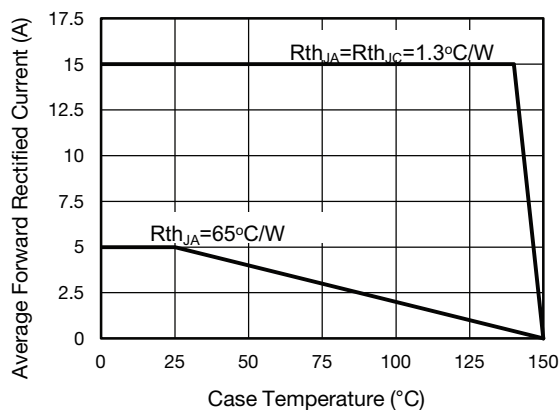
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

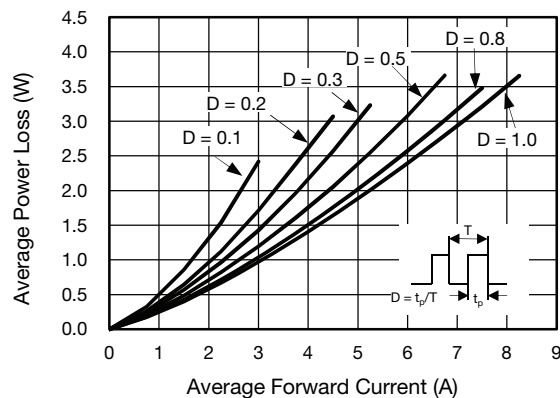


Fig. 2 - Forward Power Loss Characteristics Per Diode

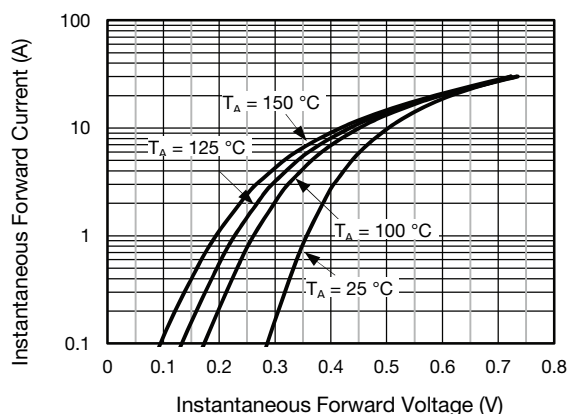


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

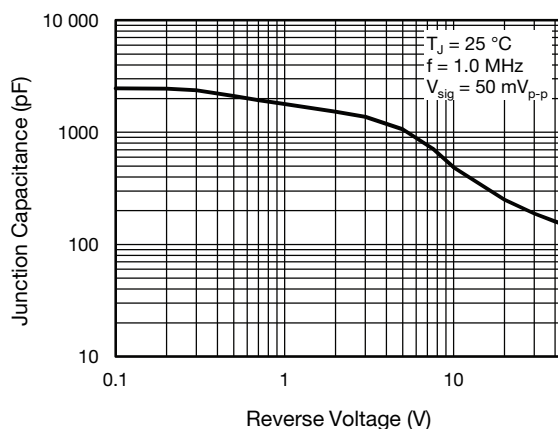


Fig. 5 - Typical Junction Capacitance Per Diode

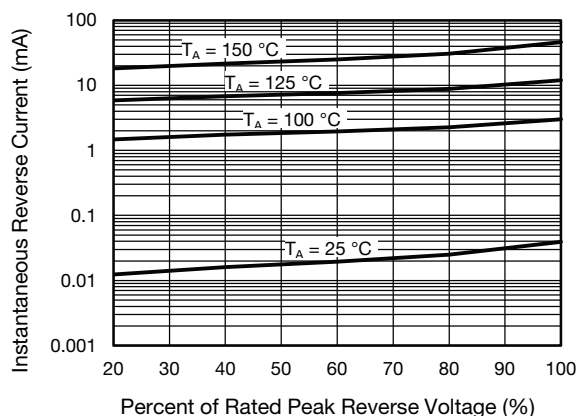


Fig. 4 - Typical Reverse Characteristics Per Diode

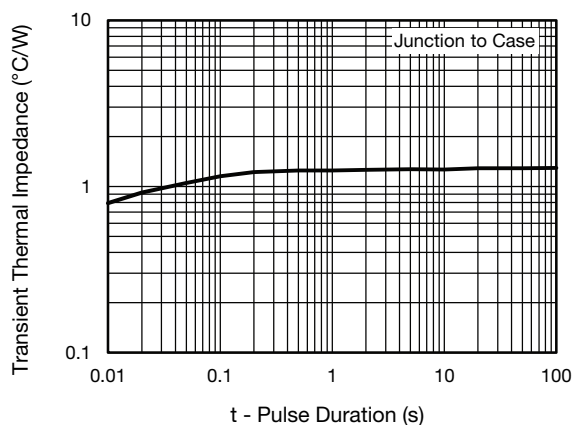
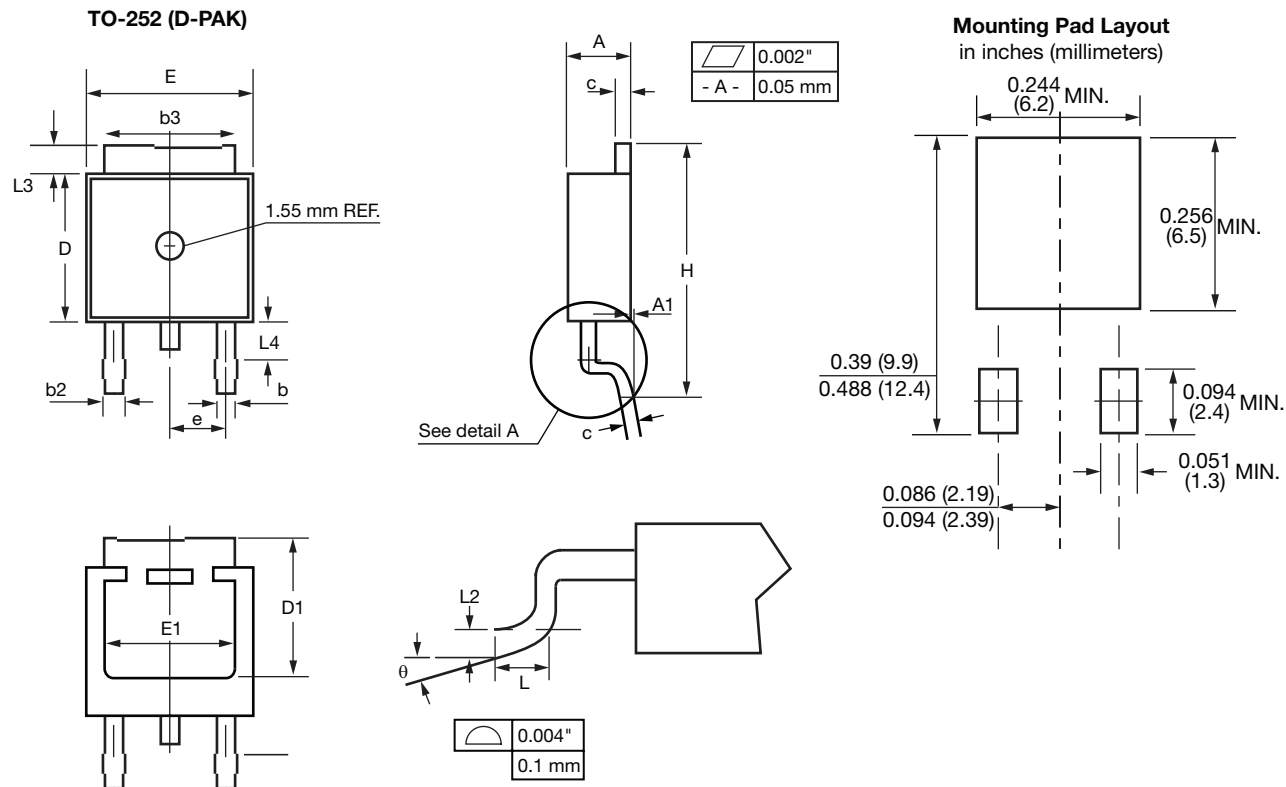


Fig. 6 - Typical Transient Thermal Impedance Per Device


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)


SYMBOL	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.086	0.094	2.19	2.38
A1	-	0.005	-	0.13
b	0.025	0.035	0.64	0.89
b2	0.033	0.045	0.84	1.14
b3	0.205	0.215	5.21	5.46
c	0.018	0.024	0.46	0.61
D	0.235	0.250	5.97	6.22
D1	0.205	-	5.21	-
E	0.250	0.265	6.35	6.73
E1	0.190	-	4.83	-
e	0.090 BSC.		2.29 BSC.	
H	0.380	0.410	9.65	10.41
L	0.055	0.070	1.40	1.78
L2	0.020 BSC.		0.51 BSC.	
L3	0.035	0.050	0.89	1.27
L4	0.025	0.039	0.64	1.01
θ	0°	8°	0°	8°

Note

- Conforms to JEDEC TO-252 variation AA except dimension "D"



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